

L Number	Hits	Search Text	DB	Time stamp
3	43268	power adj2 device	USPAT; US-PGPUB	2004/09/29 15:09
4	50377	trench\$2	USPAT; US-PGPUB	2004/09/29 15:09
5	523887	recess\$2	USPAT; US-PGPUB	2004/09/29 15:09
6	570955	groove\$1	USPAT; US-PGPUB	2004/09/29 15:10
7	391447	gate	USPAT; US-PGPUB	2004/09/29 15:11
8	22660	first adj (trench\$2 or recess\$2 or groove\$1)	USPAT; US-PGPUB	2004/09/29 15:13
9	25392	second adj (trench\$2 or recess\$2 or groove\$1)	USPAT; US-PGPUB	2004/09/29 15:14
10	4131	third adj (trench\$2 or recess\$2 or groove\$1)	USPAT; US-PGPUB	2004/09/29 15:14
11	69	(power adj2 device) and (first adj (trench\$2 or recess\$2 or groove\$1)) and (second adj (trench\$2 or recess\$2 or groove\$1)) and (third adj (trench\$2 or recess\$2 or groove\$1))	USPAT; US-PGPUB	2004/09/29 15:21
12	220594	spacer\$1	USPAT; US-PGPUB	2004/09/29 15:22
13	419	(power adj2 device) and ((trench\$2 or recess\$2 or groove\$1) same spacer\$1)	USPAT; US-PGPUB	2004/09/29 15:31
15	24246	self adj align\$2	USPAT; US-PGPUB	2004/09/29 16:57
16	22360	self?align\$2	USPAT; US-PGPUB	2004/09/29 16:57
17	208	(power adj2 device) and ((trench\$2 or recess\$2 or groove\$1) same ((self adj align\$2) or self?align\$2))	USPAT; US-PGPUB	2004/09/29 16:58

L Number	Hits	Search Text	DB	Time stamp
1	2	("20030068864").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/29 14:32
2	0	("powerandsemicondcutorand(pluralandgroove)").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/29 14:33
4	2572	(power and semiconductor) and (plural and groove)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/29 14:37
3	10	(power and semicondutor) and (plural and groove)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/29 14:34
6	71087	vertical and transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/29 14:38
7	377	((power and semiconductor) and (plural and groove)) and (vertical and transistor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/29 14:38